INTEGRATED CIRCUITS

DATA SHEET

74LV574

Octal D-type flip-flop; positive edge-trigger (3-State)

Product specification Supersedes data of 1997 Feb 03 IC24 Data Handbook





Octal D-type flip-flop; positive edge-trigger (3-State)

74LV574

FEATURES

- Wide operating voltage: 1.0 to 5.5V
- Optimized for Low Voltage applications: 1.0 to 3.6V
- ullet Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2V at V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Common 3-State output enable input
- Output capability: bus driver
- I_{CC} category: MSI

DESCRIPTION

The 74LV574 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT574.

The 74LV574 is an octal D-type flip-flop featuring separate D-type inputs for each flip-flop and non-inverting 3-state outputs for bus oriented applications. A clock (CP) and an output enable ($\overline{\text{OE}}$) input are common to all flip-flops.

The eight flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition.

When \overline{OE} is LOW, the contents of the eight flip-flops is available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the OE input does not affect the state of the flip-flops.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay CP to Q _n	$C_L = 15pF$ $V_{CC} = 3.3V$	13	ns
f _{max}	Maximum clock frequency	$C_L = 15pF, V_{CC} = 3.3V$	77	MHz
C _I	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per flip-flop	Notes 1 and 2	25	pF

NOTES:

- 1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)

 - $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; C_L = output load capacity in pF;
 - f_o = output frequency in MHz; V_{CC} = supply voltage in V; Σ ($C_L \times V_{CC}^2 \times f_o$) = sum of the outputs.
- 2. The condition is $V_I = GND$ to V_{CC}

ORDERING AND PACKAGE INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic DIL	–40°C to +125°C	74LV574 N	74LV574 N	SOT146-1
20-Pin Plastic SO	-40°C to +125°C	74LV574 D	74LV574 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +125°C	74LV574 DB	74LV574 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +125°C	74LV574 PW	74LV574PW DH	SOT360-1

PIN DESCRIPTION

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PIN NUMBER	SYMBOL	FUNCTION
1	ŌĒ	Output enabled input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	D0-D7	Data inputs
19, 18, 17, 16, 15, 14, 13, 12	Q0-Q7	3-State flip-flop outputs
10	GND	Ground (0V)
11	СР	Clock input (LOW-to-HIGH, edge-triggered)
20	VCC	Positive supply voltage

FUNCTION TABLE

OPERATING	11	NPUT:	S	INTERNAL	OUTPUTS	
MODES	OE	СР	Dn	FLIP-FLOPS	Q0 to Q7	
Load and read register	L	\uparrow	h	L H	L H	
Load register and disable outputs	H	↑	l h	L H	Z Z	

- Н HIGH voltage level
 - HIGH voltage level one set-up time prior to the
 - LOW-to-HIĞH CP transition

LOW-to-HIGH clock transition

- L LOW voltage level
 - LOW voltage level one set-up time prior to the

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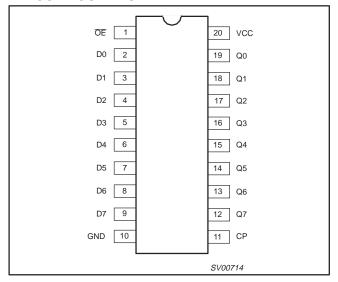
- LOW-to-HIGH CP transition
- Ζ High impedance OFF-state

h

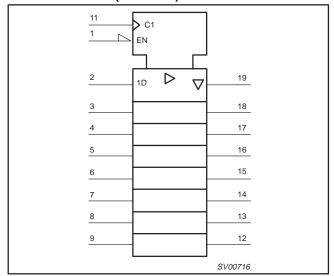
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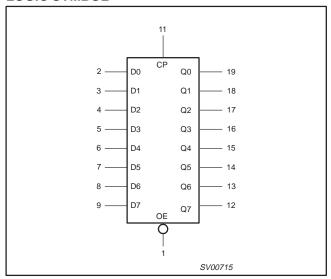
PIN CONFIGURATION



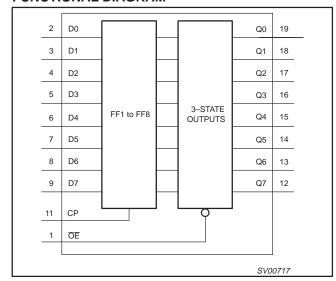
LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



FUNCTIONAL DIAGRAM



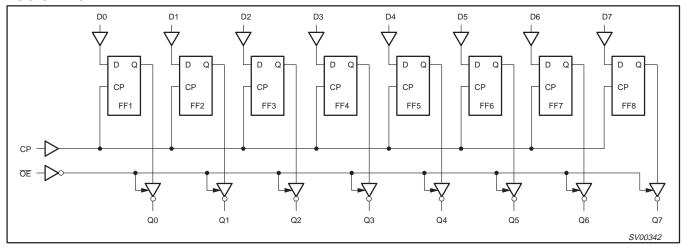
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LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
±I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
±ΙΟΚ	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5V$	50	mA
±ΙΟ	DC output source or sink current – bus driver outputs	-0.5V < V _O < V _{CC} + 0.5V	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with –bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package –plastic DIL –plastic mini-pack (SO) –plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: –40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note ¹	1.0	3.3	5.5	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	_	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$ $V_{CC} = 3.6V \text{ to } 5.5V$	- - -	- - - -	500 200 100 50	ns/V

NOTES:

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{1.} The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5V.

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DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40	°C to +8	5°C	-40°C to	+125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2V	0.9			0.9		
\/	HIGH level Input	V _{CC} = 2.0V	1.4			1.4] _v
V_{IH}	voltage	V _{CC} = 2.7 to 3.6V	2.0			2.0		1
		V _{CC} = 4.5 to 5.5V	0.7*V _{CC}			0.7*V _{CC}		1
		V _{CC} = 1.2V			0.3		0.3	
V_{IL}	LOW level Input	V _{CC} = 2.0V			0.6		0.6	
۷IL	voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$			0.8		0.8] `
		$V_{CC} = 4.5 \text{ to } 5.5$			0.3*V _{CC}		0.3*V _{CC}	
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$		1.2				
	LUCI Haval autaut	$V_{CC} = 2.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	1.8	2.0		1.8]
	HIGH level output voltage; all outputs	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	2.5	2.7		2.5]
V_{OH}		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	2.8	3.0		2.8		V
OH		$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 100 \mu A$	4.3	4.5		4.3		
	HIGH level output voltage; BUS driver	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 8\text{mA}$	2.40	2.82		2.20		
	outputs	$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 16\text{mA}$	3.60	4.20		3.50		
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0				
		$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2	1
	LOW level output voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2]
V_{OL}		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	V
OL		$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2]
	LOW level output voltage; BUS driver	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 8\text{mA}$		0.20	0.40		0.50	
	outputs	$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 16\text{mA}$		0.35	0.55		0.65	
II	Input leakage current	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND			1.0		1.0	μА
I _{OZ}	3-State output OFF-state current	V_{CC} = 5.5V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND			5		10	μА
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 5.5V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		160	μА
Δl _{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V \text{ to } 3.6V; V_I = V_{CC} - 0.6V$			500		850	μА

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NOTE:

^{1.} All typical values are measured at T_{amb} = 25°C.

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AC CHARACTERISTICS

GND = 0V; t_r = t_f \leq 2.5ns; C_L = 50pF; R_L = 1K Ω

SYMBOL	PARAMETER	WAVEFORM	CONDITION	-4	LIMITS 40 to +85 °	°C		IITS +125 °C	UNIT
			V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	
			1.2	-	80	-	-	-	
			2.0	_	27	34	-	43	
t _{PHL} /t _{PLH}	Propagation delay CP to Qn	Figure 1, 4	2.7	_	20	25	-	31	ns
	0. 10 4		3.0 to 3.6	-	15 ²	20	-	25	
			4.5 to 5.5	_	-	17	-	21	
			1.2	_	70	-	_	-	
	3-State output		2.0	-	24	34	-	43	
t _{PZH} /t _{PZL}	enable time	Figure 2, 4	2.7	_	18	25	-	31	ns
	OE to Qn		3.0 to 3.6	_	13 ²	20	_	25	
			4.5 to 5.5	_	-	17	-	21	
			1.2	-	75	-	-	-	
	3-State output		2.0	_	27	27	-	34	
t _{PHZ} /t _{PLZ}	disable time	Figure 2, 4	2.7	-	21	21	-	26	ns
	OE to Qn		3.0 to 3.6 – 16 ²		17	-	21		
			4.5 to 5.5	_	-	15	-	18	
			2.0	34	9	-	41	-	
t _W	Clock pulse width HIGH or LOW	Figure 1	2.7	25	6	-	30	-	ns
	101.01.2011		3.0 to 3.6	20	5 ²	-	24	-	
			1.2	_	10	-	_	-	
4	Set-up time	Figure 3	2.0	22	4	-	26	-	ns
t _{su}	Dn to CP	Figure 3	2.7	16	3	-	19	-	115
			3.0 to 3.6	13	2 ²	-	15	-	
			1.2	_	-10	-	_	-	
4.	Hold time	Figure 3	2.0	5	-4	-	5	-	ns
чh	t _h Dn to CP	Figure 3	2.7	5	-3	-	5	-	119
			3.0 to 3.6	5	-2 ²	-	5	-	
	Mandania		2.0	15	40	-	12	-	
f_{max}	f _{max} Maximum clock pulse frequency	Figure 1	2.7	19	58	-	16	_	MHz
		<u> </u>	3.0 to 3.6	24	70 ²	_	20	_	

Unless otherwise stated, all typical values are at T_{amb} = 25°C.
 Typical value measured at V_{CC} = 3.3V.

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AC WAVEFORMS

 $V_{M} = 1.5V$ at $V_{CC} \ge 2.7V$ and $\le 3.6V$

 V_{M} = 0.5 * V_{CC} at $V_{CC} <$ 2.7V and \geq 4.5V

 $\mbox{V}_{\mbox{\scriptsize OL}}$ and $\mbox{V}_{\mbox{\scriptsize OH}}$ are the typical output voltage drop that occur with the output load.

 $V_X = V_{OL} + 0.3V$ at $V_{CC} \ge 2.7V$ and $\le 3.6V$

 $V_X = V_{OL} + 0.1 V_{CC}$ at $V_{CC} < 2.7 V$ and $\geq 4.5 V$

 $V_Y = V_{OH} - 0.3V$ at $V_{CC} \ge 2.7V$ and $\le 3.6V$

 $V_Y = V_{OH} - 0.1 V_{CC}$ at $V_{CC} < 2.7 V$ and $\geq 4.5 V$

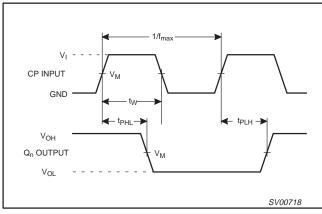


Figure 1. Clock (CP) to output (Qn) propagation delays, the clock pulse (CP) and the maximum clock pulse frequency

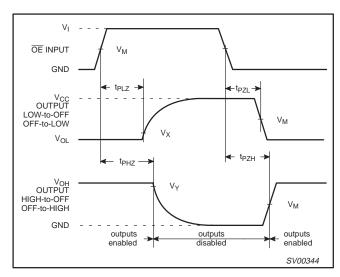


Figure 2. 3-state enable and disable times

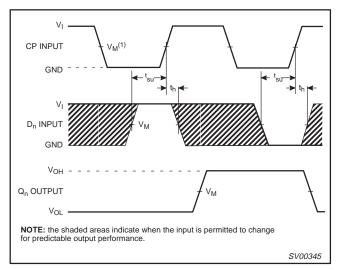


Figure 3. Data set-up and hold times for the Dn input to the CP input

NOTE:

The shaded areas indicate when the input is permitted to change for predictable output performance.

TEST CIRCUIT

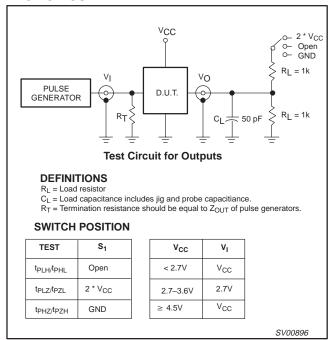


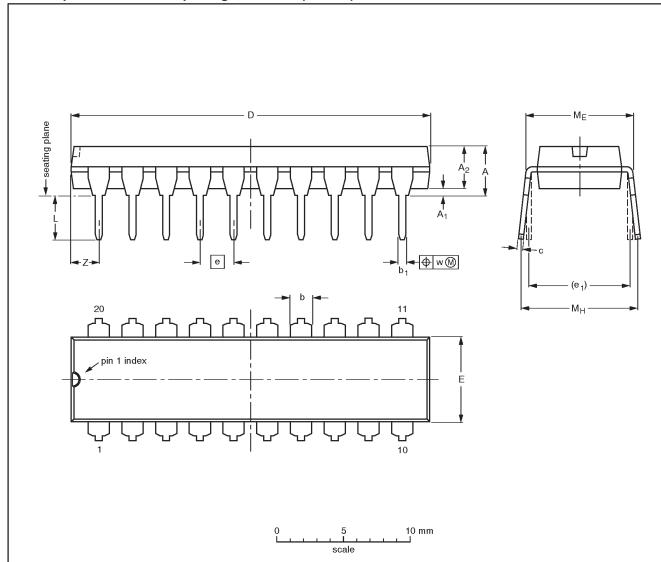
Figure 4. Load circuitry for switching times

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DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

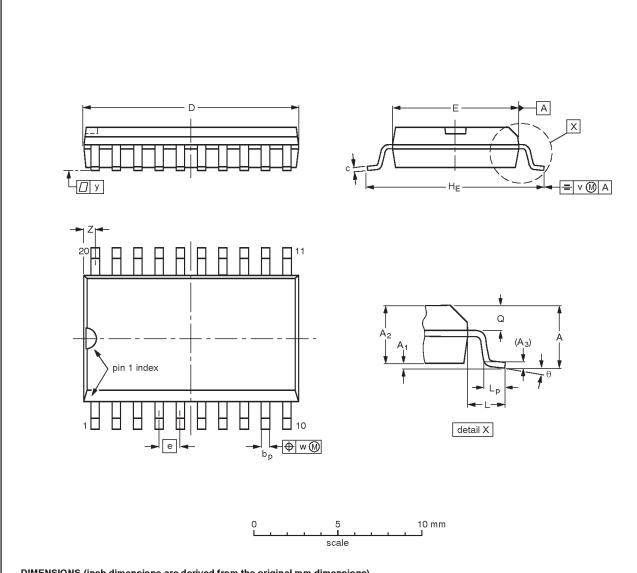
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT146-1			SC603		92-11-17 95-05-24

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	o°

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

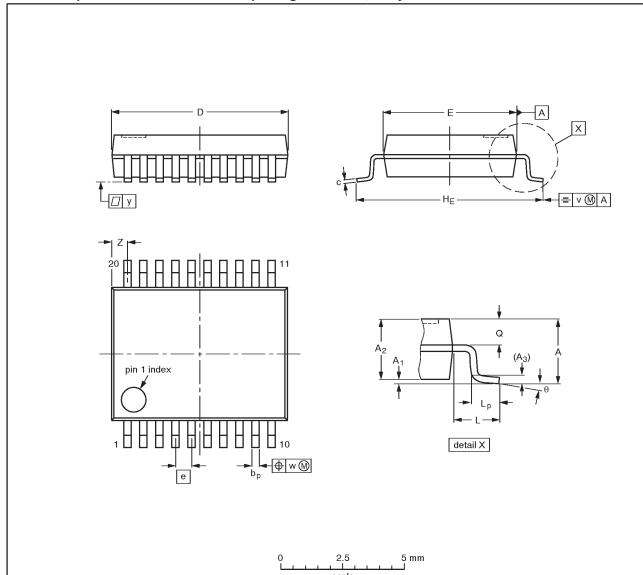
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013AC			92-11-17 95-01-24

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	А3	р _р	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	٦	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

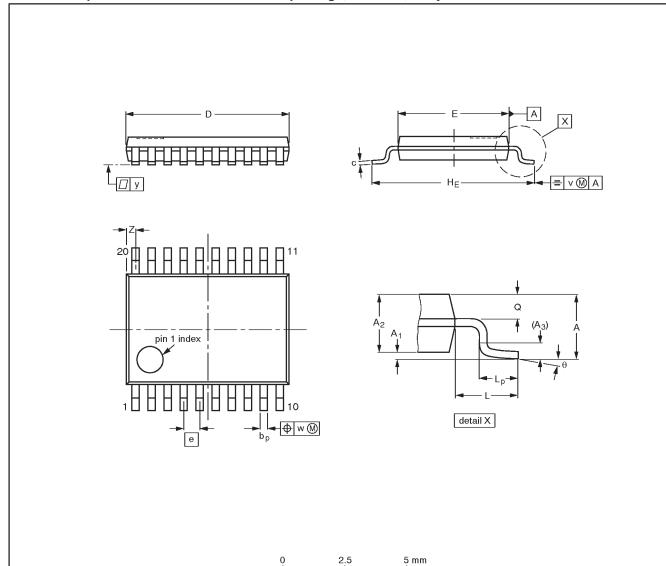
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE	
SOT339-1		MO-150AE				93-09-08 95-02-04	

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	рb	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Œ	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

scale

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT360-1		MO-153AC				-93-06-16- 95-02-04

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	DEFINITIONS							
Data Sheet Identification	Product Status	Definition						
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.						
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.						
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